

Supporting Information for

“Flat bands in bilayer graphene induced by proximity with polar *h*-BN superlattices”

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I. COMPUTATIONAL METHODOLOGY

DFT calculations were performed using the QUANTUM ESPRESSO suite^{1–3} in conjunction with the Perdew-Burke-Ernzerhof (PBE)^{4,5} exchange-correlation functional and norm-conserving pseudopotentials from PseudoDojo⁶. The vdW corrections are incorporated by employing the PBE+rVV10 method yielding excellent structural properties for layered materials^{7,8} and find the interlayer distances d between C, B, and N atoms in relaxed structures to be close to the value in bulk graphite and BN⁹, $d = 3.35 \text{ \AA}$. Data preprocessing was carried out with Atomic Simulator Environment (ASE)¹⁰. For the self-consistent calculations, we set the plane-waves basis cutoff to 80 Ry and used a fine Monkhorst-Pack \mathbf{k} -point grid of $(90 \times 90 \times 1)$. We verified that a vacuum region of thickness of 28 Å and 22 Å for 2h-BN/BLG/2h-BN and 2h-BN/BLG systems, respectively, is sufficient to avoid interactions between periodic images. Tight DFT convergence parameters were necessary to obtain consistent results for symmetry-related configurations. The Wannierization procedure was performed by employing the Wannier90 code¹¹. The on-site matrix elements of an *ab initio* Hamiltonian were used to construct TB models within Pybinding package¹². To solve a large-scale diagonalization problem, we used the FEAST algorithm¹³.

II. EQUILIBRIUM INTERLAYER DISTANCE IN *h*-BN SYSTEMS

The vertical polarization P_z in layered materials was found to depend strongly on the interlayer distance d , and the optimal distance d_0 considerably depends on how the vdW interactions are incorporated in the calculations. As (semi)-local functionals cannot correctly describe the long-range vdW interactions¹⁴, we systematically study various empirical correction schemes and non-local functionals in order to determine d_0 (at fixed intralayer lattice constant $a = 2.46 \text{ \AA}$) and the binding energies E_b of bulk and bilayer 2h-BN systems in AB and AA' stacking configurations. We define the binding energy as

$$E_b = E_{2h-\text{BN}}(d_0) - E_{h-\text{BN}}, \quad (1)$$

where $E_{2h-\text{BN}}$ is the energy of a two-layered system at optimal spacing d_0 , and $E_{h-\text{BN}}$ corresponds to the energy of a monolayer. As a reference system (monolayer), we use a supercell with two equally separated *h*-BN layers by a distance $d = 16 \text{ \AA}$. We carried out calculations for the binding energies of bulk and bilayer geometries

using \mathbf{k} -point meshes of $(27 \times 27 \times 9)$ and $(27 \times 27 \times 1)$, respectively. The results for dispersion-corrected LDA and PBE functionals^{15–21} as well as for vdW functionals^{7,8,22–29} are given in Table I.

The calculated values of d_0 are in agreement with previous reports^{30–33}. We recall that the experimentally determined interlayer distance in bulk *h*-BN (AA' configuration) is 3.33 \AA ^{34,35}, which is closely reproduced by random phase approximation (RPA) calculations, $d_0 = 3.34 \text{ \AA}$ ³². In general, the interlayer spacings d_0 tend to be larger for AA' stacking order than AB; a similar trend is observed between bilayer and bulk geometries for the same stacking configurations.

We find that the binding energies are weaker in *h*-BN bilayers than in bulk systems. LDA functional in combination with DFT-D2 approach of Grimme (LDA-D2) yields overestimated values of E_b , while PBE is underbinding. We include these results solely for the purpose of conducting systematic investigations. The obtained binding energies using PBE+Grimme corrections and vdW-DFs functionals are consistent with Refs. 25, 32, and 33. However, our calculated binding energies using PBE-TS method are significantly lower than the values reported in previous articles^{30,33}. We relate these differences to different computational setups employed between our study and other works. Ref. 36 reports interlayer binding energy from RPA calculations to be 39 meV/atom.

III. POLARIZATION IN MULTILAYERED GRAPHENE/*h*-BN STRUCTURES

A commonly used approach to compute the polarization within the DFT framework deals with the Berry phase^{37,38}. However, this method can be applied only to insulating systems. In this work, we estimate the vertical polarization P_z from the dipole corrections for a slab^{39–41}. We summarize the results in Tables II and III. We indicate the stacking orders discussed in the main text by bold font. We stress that for symmetry-related 2h-BN/BLG/2h-BN structures, P_z must be the same, but with opposite sign. A small discrepancy between these values up to 3% is due to numerical accuracy. For the sake of completeness, we also report the results for 8 stackings with inversion symmetry. As expected, P_z and ΔE are practically zero.

It is important to stress that for *h*-BN bilayers (with large ΔE), the values of P_z obtained from dipole corrections and the Berry phase calculations with artificially

TABLE I. Equilibrium interlayer distance d_0 and binding energy E_b for bulk and bilayer 2h-BN calculated using different dispersion corrections and non-local exchange-correlation functionals. All the binding energies are given in meV per atom in the four-atom unit cell.

	bulk				bilayer			
	AA'		AB		AA'		AB	
	d_0 [Å]	E_b [meV/atom]						
LDA	3.22	-26.8	3.22	-27.7	3.25	-13.4	3.22	-13.9
LDA-D2	2.91	-143.0	2.88	-148.7	2.94	-65.9	2.89	-69.0
PBE	4.22	-1.8	4.22	-1.7	4.22	-0.9	4.22	-0.8
PBE-D2	3.08	-82.1	3.04	-84.5	3.11	-36.8	3.07	-37.9
PBE-D3	3.41	-42.3	3.40	-42.3	3.43	-20.2	3.42	-20.3
PBE-D3 (BJ)	3.33	-45.3	3.31	-45.9	3.35	-21.6	3.33	-21.9
PBE-D3M	3.27	-41.9	3.25	-42.6	3.29	-20.1	3.26	-20.4
PBE-D3M (BJ)	3.25	-48.0	3.23	-48.8	3.26	-23.0	3.24	-23.4
PBE-TS	3.33	-32.2	3.30	-32.6	3.37	-14.2	3.37	-14.3
PBE-MBD	3.45	-23.7	3.45	-23.9	3.44	-11.0	3.44	-11.1
vdW-DF	3.55	-53.3	3.53	-53.2	3.57	-24.0	3.56	-23.9
vdW-DF2	3.48	-52.0	3.48	-51.8	3.51	-23.7	3.50	-23.5
vdW-DF-C09	3.17	-76.4	3.15	-77.7	3.20	-34.4	3.17	-35.1
vdW-DF2-C09	3.22	-55.2	3.20	-55.3	3.25	-24.4	3.23	-24.8
rev-vdW-DF2	3.27	-59.2	3.25	-59.9	3.30	-26.6	3.28	-26.9
vdW-DF-cx	3.22	-65.5	3.20	-66.6	3.25	-29.2	3.23	-29.6
optB88-vdW	3.29	-70.5	3.28	-70.9	3.31	-31.9	3.30	-32.1
optB86b-vdW	3.25	-70.7	3.24	-71.4	3.28	-31.9	3.26	-32.2
vdW-DF3-opt1	3.25	-56.0	3.23	-56.7	3.26	-25.9	3.25	-26.3
vdW-DF3-opt2	3.24	-61.2	3.22	-62.0	3.27	-28.0	3.25	-28.3
rVV10	3.30	-69.8	3.29	-70.4	3.35	-30.1	3.34	-30.3

TABLE II. Vertical polarizations per area P_z/A and energy gaps ΔE of 2h-BN/BLG heterostructures.

stacking	P_z/A [pC/m]	ΔE [meV]
ABAB	0.125	15.65
ABAC	0.296	39.90
ABC A	-1.711	10.43
ABCB	-1.311	21.13
ACAB	0.564	3.31
ACAC	0.948	26.96
ACBA	2.555	46.42
ACBC	2.386	21.45

introduced k -point sampling along z -axis are essentially the same. However, for graphene/ h -BN structures char-

acterized by small ΔE , the values of P_z obtained from the Berry phase calculations is more sensitive to the computational parameters.

IV. WANNIER FUNCTIONS ANALYSIS

To ensure the high quality of the Wannier functions and the convergence of the on-site energies, we performed wannierization on the $30 \times 30 \times 1$ k -point meshes and chose the frozen window such that its edges are 1 meV away from the closest bands outside of the window. The resulting Wannier functions are atomic-like, with a total spread below 7 \AA^2 . In Tables IV and V, we list the potential differences $\Delta V_{\text{sublattice},U/L}$ and Δ_{layer} for all configurations considered.

TABLE III. Vertical polarization per area P_z/A and energy gap ΔE calculated for 2h-BN/BLG/2h-BN heterostructures in various stacking configurations.

stacking	P_z/A [pC/m]	ΔE [meV]	stacking	P_z/A [pC/m]	ΔE [meV]
ABABAB	-0.939	5.12	ABABAC	1.483	7.14
ACACAC	0.936	5.02	ABCBCB	-1.494	7.01
ABABCA	-2.583	23.42	ABABC B	-0.270	18.56
ACBABA	2.589	23.38	ABACAC	0.273	18.35
ABACAB	-2.062	14.47	ABACBA	1.977	57.43
ACBCAC	2.064	14.66	ABCABA	-1.982	57.44
ABACBC	-0.364	51.74	ABCABC	-4.296	62.35
ACACBC	0.355	52.20	ACBACB	4.296	61.84
ABCACA	-2.659	42.96	ABCACB	-0.341	38.88
ACACBA	2.641	43.14	ABC BAC	0.335	38.52
ABC BAB	-2.020	34.08	ABCBCA	-3.808	3.15
ACABAC	2.013	34.00	ACBCBA	3.804	3.31
ACABAB	-0.331	37.78	ACABCA	-1.955	57.61
ACACBC	0.330	37.83	ACBACA	1.970	56.88
ACACAB	-1.482	6.95	ACBABC	0.283	19.06
ACBCBC	1.475	7.19	ACBCAB	-0.274	19.26
ABABA'C'	-2.319	3.96	ABCBC'B'	-2.326	2.34
ACBCB'C'	2.320	4.01	ACACA'B'	2.327	2.24
ABABC'A'	1.792	31.94	ACBAB'A'	1.724	10.84
ABCAC'A'	-1.802	31.91	ACACB'A'	-1.725	11.00
ABABC'B'	-0.536	26.83	ABACA'C'	-0.593	5.71
ACABA'B'	0.537	26.60	ACACBC	0.587	5.65
ABACA'B'	1.732	9.99	ACBCA'C'	1.777	31.25
ABCBA'B'	-1.738	10.04	ACABA'C'	-1.786	31.08
ABACB'A'	-2.328	3.79	ABCAB'A'	-2.428	< 1
ACBAC'A'	2.325	3.78	ACABC'A'	2.422	< 1
ABCAC'B'	-4.109	36.02	ABCBA'C'	-4.069	14.10
ACBCA'B'	4.110	35.89	ACBAB'C'	4.054	14.29
ABABA'B'	-0.001	< 1	ACACA'C'	-0.004	< 1
ABACB'C'	-0.002	< 1	ACABC'B'	-0.002	< 1
ABCAB'C'	-0.005	< 1	ACBAC'B'	0.003	< 1
ABCBC'A'	-0.007	< 1	ACBCB'A'	0.003	< 1

V. REAL-SPACE LOCALIZATION OF THE FLAT-BAND STATES

In Fig. 1, we show the sum of probability densities of two-fold degenerate eigenstates ψ_i at the Γ point, $|\psi_i(\mathbf{r}, \mathbf{k} = 0)|^2$ at $L = 50$ nm. These states are mostly localized in the centers or the corners of triangular domains, rather than at their edges.

VI. BAND STRUCTURES OF PRIMED CONFIGURATIONS

We now comment on the band structures corresponding to the configurations that break inversion symmetry only weakly. The results are qualitatively different from

those for non-primed stacking configurations as these systems at large L remain gapless and no separated flat bands are observed (see Fig. 2), despite comparable values of the potential differences. This underlines the importance of local atomic environment on the electronic properties in the discussed structures.

TABLE IV. On-site energy differences of the p_z orbitals of C atoms in 2h-BN/BLG heterostructures.

stacking	$\Delta V_{\text{sublattice,U}}$ [meV]	$\Delta V_{\text{sublattice,L}}$ [meV]	Δ_{layer} [meV]
ABAB	-1.53	11.84	10.82
ABAC	-0.37	-8.81	21.74
ABC A	-1.04	43.26	-4.34
ABC B	0.60	-40.27	21.46
ACAB	-1.21	43.97	-16.64
ACAC	0.56	-41.07	10.63
ACBA	0.14	-7.72	14.95
ACBC	-0.80	9.33	4.43

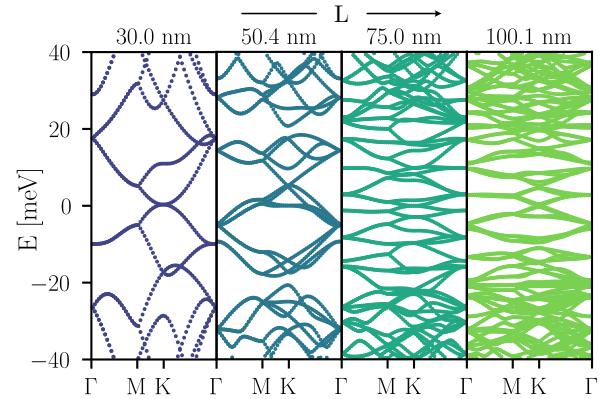


FIG. 2. Band structures as a function of L for the ABCAB'C' configuration. At $L = 30$ nm, the parabolic band touching at K is present, which further evolves into a linear crossing.

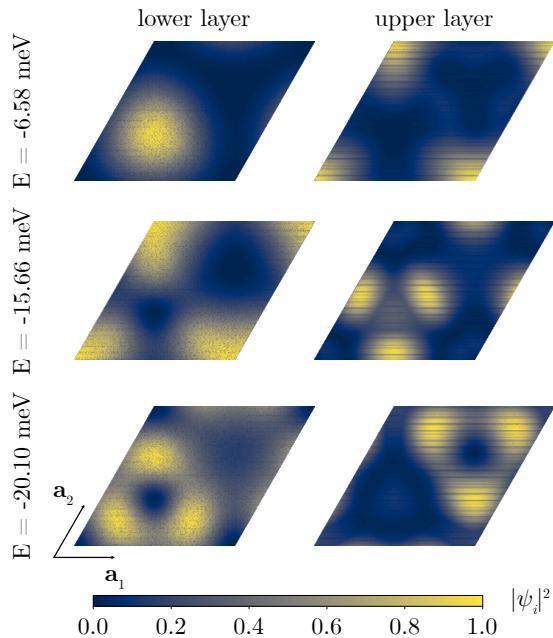


FIG. 1. Electronic density $|\psi_i(\mathbf{r})|^2$ of the states from the marked flat bands subspaces (consult Fig. 2(c) of the main text). The color scale corresponds to the normalized square modulus $|\psi_i(\mathbf{r})|^2$ of the wave function. The localization pattern exhibits a C_3 -rotational symmetry.

TABLE V. On-site energy differences of the p_z orbitals of C atoms in 2h-BN/BLG/2h-BN heterostructures.

stacking	$\Delta V_{\text{sublattice,U}}$ [meV]	$\Delta V_{\text{sublattice,L}}$ [meV]	Δ_{layer} [meV]	stacking	$\Delta V_{\text{sublattice,U}}$ [meV]	$\Delta V_{\text{sublattice,L}}$ [meV]	Δ_{layer} [meV]
ABABAB	36.89	6.09	-3.13	ABABAC	36.4	6.23	-1.01
ACACAC	-6.11	-36.94	3.25	ABCBCB	-6.25	-36.43	1.17
ABABCA	5.03	7.42	-13.47	ABABCB	5.88	7.26	-17.00
ACBABA	-7.41	-5.08	13.53	ABACAC	-7.34	-5.89	17.28
ABACAB	-6.69	-5.80	20.13	ABACBA	-37.08	-4.98	31.83
ACBCAC	5.78	6.65	-19.90	ABCABA	4.95	37.06	-31.81
ABACBC	-37.51	-5.34	38.47	ABCABC	4.70	36.09	-32.45
ACACBC	5.32	37.45	-37.91	ACBACB	-36.09	-4.74	33.06
ABCACA	36.42	36.28	-19.91	ABCACB	36.63	37.16	-23.94
ACACBA	-36.31	-36.46	19.72	ABCBCA	-37.19	-36.67	24.33
ABCBAB	-37.10	-35.85	27.10	ABCBCA	-6.00	-35.28	0.47
ACABAC	35.81	37.07	-27.17	ACBCBA	35.2	5.97	-0.24
ACABAB	35.96	37.54	-23.95	ACABCA	4.61	37.57	-37.31
ACACBC	-37.58	-36.01	23.94	ACBACA	-37.57	-4.66	38.14
ACACAB	-5.76	-36.47	-3.51	ACBABC	-6.22	-6.64	17.98
ACBCBC	36.43	5.74	3.79	ACBCAB	6.64	6.19	-17.75
ABABA'C'	-6.19	7.46	3.56	ABCBC'B'	37.25	-36.62	4.04
ACBCB'C'	-7.49	6.18	-3.59	ACACA'B'	36.60	-37.28	-3.90
ABABC'A'	-36.73	7.30	21.74	ACBAB'A'	35.40	-5.57	20.71
ABCAC'A'	-7.29	36.70	-21.76	ACACB'A'	5.57	-35.46	-20.49
ABABC'B'	-37.88	7.38	26.01	ABACA'C'	37.31	-6.12	19.51
ACABA'B'	-7.39	37.82	-26.23	ACACB'C'	6.10	-37.36	-19.52
ABACA'B'	36.47	-6.09	14.90	ACBCA'C'	-37.71	7.76	25.24
ABCBA'B'	6.07	-36.49	-14.81	ACABA'C'	-7.78	37.70	-25.42
ABACB'A'	5.46	-6.74	3.09	ABCAB'A'	-38.16	36.95	-2.22
ACBAC'A'	6.73	-5.46	-3.06	ACABC'A'	-37.02	38.09	1.60
ABCAC'B'	-7.06	35.73	-21.65	ABCBA'C'	5.61	-35.32	-16.27
ACBCA'B'	-35.77	7.01	21.80	ACBAB'C'	35.27	-5.68	16.11
ABABA'B'	-7.40	7.37	0.05	ACACAA'C'	36.98	-37.02	-0.02
ABACB'C'	6.24	-6.28	0.04	ACABC'B'	-37.82	37.80	0.06
ABCAB'C'	-38.05	38.02	0.07	ACBAC'B'	6.56	-6.60	0.08
ABCBC'A'	37.45	-37.49	0.02	ACBCB'A'	-5.55	5.52	0.07

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